## Data Sheet

## Description

The APDS-9900/9901 provides digital ambient light sensing (ALS), IR LED and a complete proximity detection system in a single 8 pin package. The proximity function offers plug and play detection to 100 mm (without front glass) thus eliminating the need for factory calibration of the end equipment or sub-assembly. The proximity detection feature operates well from bright sunlight to dark rooms. The wide dynamic range also allows for operation in short distance detection behind dark glass such as a cell phone. In addition, an internal state machine provides the ability to put the device into a low power mode in between ALS and proximity measurements providing very low average power consumption. The ALS provides a photopic response to light intensity in very low light condition or behind a dark faceplate.

The APDS-9900/9901 is particularly useful for display management with the purpose of extending battery life and providing optimum viewing in diverse lighting conditions. Display panel and keyboard backlighting can account for up to 30 to 40 percent of total platform power. The ALS features are ideal for use in notebook PCs, LCD monitors, flat-panel televisions, and cell phones.

The proximity function is targeted specifically towards near field proximity applications. In cell phones, the proximity detection can detect when the user positions the phone close to their ear. The device is fast enough to provide proximity information at a high repetition rate needed when answering a phone call. This provides both improved "green" power saving capability and the added security to lock the computer when the user is not present. The addition of the micro-optics lenses within the module, provide highly efficient transmission and reception of infrared energy which lowers overall power dissipation.

## Ordering Information

| Part Number | Packaging | Quantity |
| :--- | :--- | :--- |
| APDS-9900 | Tape \& Reel | 2500 per reel |
| APDS-9901 | Tape \& Reel | 2500 per reel |



## Features

ALS, IR LED and Proximity Detector in an Optical Module

- Ambient Light Sensing (ALS)
- Approximates Human Eye Response
- Programmable Interrupt Function with Upper and Lower Threshold
- Up to 16-Bit Resolution
- High Sensitivity Operates Behind Darkened Glass
- Up to 1,000,000:1 Dynamic Range
- Proximity Detection
- Fully Calibrated to 100 mm Detection
- Integrated IR LED and Synchronous LED Driver
- Eliminates "Factory Calibration" of Prox
- Covers a 2000:1 Dynamic Range
- Programmable Wait Timer
- Wait State Power - $70 \mu \mathrm{~A}$ Typical
- Programmable from 2.72 ms to $>6 \mathrm{Sec}$
- $1^{2}$ C Interface Compatible
- Up to 400 kHz ( ${ }^{2}$ C Fast-Mode)
- Dedicated Interrupt Pin
- Sleep Mode Power - $2.5 \mu \mathrm{~A}$ Typical
- Small Package L3.94 x W2.36 x H1.35 mm


## Applications

- Cell Phone Backlight Dimming
- Cell Phone Touch-screen Disable
- Notebook/Monitor Security
- Automatic Speakerphone Enable
- Automatic Menu Pop-up
- Digital Camera Eye Sensor



## Functional Block Diagram



## Detailed Description

The APDS-9900/9901 light-to-digital device provides on-chip Ch0 and Ch1 diodes, integrating amplifiers, ADCs, accumulators, clocks, buffers, comparators, a state machine and an $I^{2} \mathrm{C}$ interface. Each device combines one Ch0 photodiode (visible plus infrared) and one Ch1 infra-red-responding (IR) photodiode. Two integrating ADCs simultaneously convert the amplified photodiode currents to a digital value providing up to 16-bits of resolution. Upon completion of the conversion cycle, the conversion result is transferred to the Ch 0 and CH 1 data registers. This digital output can be read by a microprocessor where the illuminance (ambient light level) in Lux is derived using an empirical formula to approximate the human eye response.

Communication to the device is accomplished through a fast (up to 400 kHz ), two-wire $\mathrm{I}^{2} \mathrm{C}$ serial bus for easy connection to a microcontroller or embedded controller. The digital output of the APDS-9900/9901 device is inherently more immune to noise when compared to an analog interface.

The APDS-9900/9901 provides a separate pin for level-style interrupts. When interrupts are enabled and a pre-set value is exceeded, the interrupt pin is asserted and remains asserted until cleared by the controlling firmware.

The interrupt feature simplifies and improves system efficiency by eliminating the need to poll a sensor for a light intensity or proximity value. An interrupt is generated when the value of an ALS or proximity conversion exceeds either an upper or lower threshold. Additionally, a programmable interrupt persistence feature allows the user to determine how many consecutive exceeded thresholds are necessary to trigger an interrupt. Interrupt thresholds and persistence settings are configured independently for both ALS and proximity.
Proximity detection is fully provided with an 850 nm IR LED. An internal LED driver (LDR) pin, is jumper connected to the LED cathode (LED K) to provide a factory calibrated proximity of $100+/-20 \mathrm{~mm}$. This is accomplished with a proprietary current calibration technique that accounts for all variances in silicon, optics, package and most importantly IR LED output power. This will eliminate or greatly reduce the need for factory calibration that is required for most discrete proximity sensor solutions. While the APDS9900/9901 is factory calibrated at a given pulse count, the number of proximity LED pulses can be programmed from 1 to 255 pulses, which will allow greater proximity distances to be achieved. Each pulse has a $16 \mu \mathrm{~s}$ period.

## I/O Pins Configuration

| PIN | NAME | TYPE | DESCRIPTION |
| :---: | :---: | :---: | :---: |
| 1 | SDA | I/O | ${ }^{12} \mathrm{C}$ serial data I/O terminal - serial data I/O for ${ }^{12} \mathrm{C}$. |
| 2 | INT | 0 | Interrupt - open drain. |
| 3 | LDR | 1 | LED driver for proximity emitter - up to 100 mA , open drain. |
| 4 | LEDK | 0 | LED Cathode, connect to LDR pin in most systems to use internal LED driver circuit |
| 5 | LEDA | 1 | LED Anode, connect to $\mathrm{V}_{\text {BATT }}$ on PCB |
| 6 | GND |  | Power supply ground. All voltages are referenced to GND. |
| 7 | SCL | I | $1^{2} \mathrm{C}$ serial clock input terminal - clock signal for $1^{2} \mathrm{C}$ serial data. |
| 8 | $\mathrm{V}_{\mathrm{DD}}$ |  | Power Supply voltage. |

Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted) ${ }^{\dagger}$

| Parameter | Symbol | Min | Max | Units | Test Conditions |
| :--- | :--- | :--- | :---: | :--- | :--- |
| Power Supply voltage | $\mathrm{V}_{\mathrm{DD}}$ |  | 3.8 | V | $[1]$ |
| Digital voltage range |  | -0.5 | 3.8 | V |  |
| Digital output current | IO | -1 | 20 | mA |  |
| Storage temperature range | Tstg | -40 | 85 | ${ }^{\circ} \mathrm{C}$ |  |

$\dagger$ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
Note:

1. All voltages are with respect to GND.

## Recommended Operating Conditions

| Parameter | Symbol | Min | Typ | Max | Units |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Operating Ambient Temperature | $\mathrm{T}_{\mathrm{A}}$ | -30 |  | 85 | ${ }^{\circ} \mathrm{C}$ |
| Supply voltage | $\mathrm{V}_{\mathrm{DD}}$ | 2.5 | 3.0 | 3.6 | V |
| Supply Voltage Accuracy, $\mathrm{V}_{\mathrm{DD}}$ <br> total error including transients |  | -3 |  | +3 | $\%$ |
| LED Supply Voltage | $\mathrm{V}_{\text {BATT }}$ | 2.5 |  | 4.5 | V |

## Available Options

| Part Number | Interface Description |
| :--- | :--- |
| APDS-9901 | I2C VBUS = VDD Interface |
| APDS-9900 | I2C 1.8V VBUS Interface |

## Operating Characteristics, $\mathrm{V}_{\mathrm{DD}}=\mathbf{3 V}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ (unless otherwise noted)

| Parameter | Symbol | Min | Typ | Max | Units | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply current ${ }^{[1]}$ | IDD |  | 175 | 250 | $\mu \mathrm{A}$ | Active (ATIME=0xdb, 100ms) |
|  |  |  | 70 |  |  | Wait Mode |
|  |  |  | 2.5 | 4.0 |  | Sleep Mode |
| INT SDA output low voltage | VoL | 0 |  | 0.4 | V | 3 mA sink current |
|  |  | 0 |  | 0.6 |  | 6 mA sink current |
| Leakage current, SDA, SCL, INT Pins | $\mathrm{I}_{\text {LEAK }}$ | -5 |  | 5 | $\mu \mathrm{A}$ |  |
| SCL, SDA input high voltage | $\mathrm{V}_{\mathrm{IH}}$ | 0.7 V ${ }_{\text {BUS }}$ |  |  | V | APDS-9901 |
|  |  | 1.25 |  |  |  | APDS-9900 |
| SCL, SDA input low voltage, | $\mathrm{V}_{\text {IL }}$ |  |  | $0.3 \mathrm{~V}_{\text {BUS }}$ | V | APDS-9901 |
|  |  |  |  | 0.54 |  | APDS-9900 |
| Oscillator frequency | fosc | 705 | 750 | 795 | kHz | PON = 1 |

## Note:

1. The power consumption is raised by the programmed amount of Proximity LED Drive during the 8 us the LED pulse is on. The nominal and maximum values are shown under Proximity Characteristics. There the IDD supply current is $l_{D D}$ Active + Proximity LED Drive programmed value.

ALS Characteristics, $V_{D D}=3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, Gain = 16, $\mathrm{AEN}=1$ (unless otherwise noted)

| Parameter | Channel | Min | Typ | Max | Units | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dark ALS ADC count value | Ch0 | 0 | 1 | 5 | counts | $\begin{aligned} & \mathrm{Ee}=0, \mathrm{AGAIN}=120 \mathrm{x} \\ & \text { ATIME }=0 \times \mathrm{DB}(100 \mathrm{~ms}) \end{aligned}$ |
|  | Ch1 | 0 | 1 | 5 |  |  |
| ALS ADC Integration Time Step Size |  | 2.58 | 2.72 | 2.90 | ms | ATIME $=0 x f f$ |
| ALS ADC Number of Integration Steps |  | 1 |  | 256 | steps |  |
| Full Scale ADC Counts per Step |  |  |  | 1023 | counts |  |
| Full scale ADC count value |  |  |  | 65535 | counts | ATIME $=0 \times C 0$ |
| ALS ADC count value | Ch0 | 4000 | 5000 | 6000 | counts | $\begin{aligned} & \lambda p=640 \mathrm{~nm}, \mathrm{Ee}=56 \mu \mathrm{~W} / \mathrm{cm} 2, \\ & \text { ATIME }=0 \times F 6(27 \mathrm{~ms}), \mathrm{GAIN}=16 \mathrm{x} \end{aligned}$ |
|  | Ch1 |  | 790 |  |  |  |
|  | Ch0 | 4000 | 5000 | 6000 |  | $\begin{aligned} & \lambda p=850 \mathrm{~nm}, \mathrm{Ee}=79 \mu \mathrm{~W} / \mathrm{cm} 2, \\ & \text { ATIME }=0 \times F 6(27 \mathrm{~ms}), \mathrm{GAIN}=16 \mathrm{x} \end{aligned}$ |
|  | Ch1 |  | 2800 |  |  |  |
| ALS ADC count value ratio: Ch1/Ch0 |  | 10.8 | 15.8 | 20.8 | \% | $\lambda \mathrm{p}=640 \mathrm{~nm}$, ATIME $=0 \times \mathrm{F6}(27 \mathrm{~ms})$ |
|  |  | 41 | 56 | 68 |  | $\lambda \mathrm{p}=850 \mathrm{~nm}$, ATIME $=0 \times \mathrm{F6}(27 \mathrm{~ms})$ |
| Irradiance Responsivity: Re | Ch0 |  | 29.1 |  | Counts per ( $\mu \mathrm{W} / \mathrm{cm}^{2}$ ) | $\lambda \mathrm{p}=640 \mathrm{~nm}$, ATIME $=0 \times \mathrm{F} 6$ ( 27 ms ) |
|  | Ch1 |  | 4.6 |  |  |  |
|  | Ch0 |  | 22.8 |  |  | $\lambda \mathrm{p}=850 \mathrm{~nm}$, ATIME $=0 \times F 6$ ( 27 ms ) |
|  | Ch1 |  | 12.7 |  |  |  |
| Gain scaling, relative to $1 \times$ gain setting |  | -5 |  | 5 | \% | 8 x |
|  |  | -5 |  | 5 |  | 16x |
|  |  | -5 |  | 5 |  | 120x |

## Notes:

1. Optical measurements are made using small-angle incident radiation from light-emitting diode optical sources. Visible 640 nm LEDs and infrared 850 nm LEDs are used for final product testing for compatibility with high-volume production.
2. The 640 nm irradiance Ee is supplied by an AllnGaP light-emitting diode with the following characteristics: peak wavelength $=640 \mathrm{~nm}$ and spectral halfwidth $1 / 2=17 \mathrm{~nm}$.
3. The 850 nm irradiance Ee is supplied by a GaAs light-emitting diode with the following characteristics: peak wavelength $=850 \mathrm{~nm}$ and spectral halfwidth $1 / 2=40 \mathrm{~nm}$.
4. The specified light intensity is $100 \%$ modulated by the pulse output of the device so that during the pulse output low time, the light intensity is at the specified level, and zero otherwise.

Proximity Characteristics, $\mathrm{V}_{\mathrm{DD}}=3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, PGAIN $=1, \mathrm{PEN}=1$ (unless otherwise noted)

| Parameter | Min | Typ | Max | Units | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: |
| IDD Supply current - LDR Pulse On |  | 3 |  | mA |  |
| ADC Conversion Time Step Size |  | 2.72 |  | ms | PTIME $=0 \times \mathrm{ff}$ |
| ADC Number of Integration Steps |  | 1 |  | steps | PTIME $=0 \times f f$ |
| Full Scale ADC Counts |  |  | 1023 | counts | PTIME $=0 x f f$ |
| Proximity IR LED Pulse Count | 0 |  | 255 | pulses |  |
| Proximity Pulse Period |  | 16.3 |  | $\mu \mathrm{s}$ |  |
| Proximity Pulse - LED On Time |  | 7.2 |  | $\mu \mathrm{s}$ |  |
| Proximity LED Drive |  | 100 |  | mA | PDRIVE $=0$ I SINK Sink current @ 600 mV , |
|  |  | 50 |  |  | PDRIVE $=1 \quad$ LDR Pin |
|  |  | 25 |  |  | PDRIVE $=2$ |
|  |  | 12.5 |  |  | PDRIVE $=3$ |
| Proximity ADC count value, no object |  | 100 |  |  | LED driving 8 pulses, PDRIVE $=0$, open view (no glass) and no reflective object above the module. |
| Proximity ADC count value, 100 mm distance object | 416 | 520 | 624 | counts | Reflecting object $-73 \mathrm{~mm} \times 83 \mathrm{~mm}$ Kodak $90 \%$ grey card, 100 mm distance, LED driving 8 pulses, PDRIVE $=0$, open view (no glass) above the module. |

IR LED Characteristics, $\mathrm{V}_{\mathrm{DD}}=\mathbf{3} \mathbf{V}, \mathrm{T}_{\mathrm{A}}=\mathbf{2 5 C}$

| Parameter | Min | Typ | Max | Units | Test Conditions |
| :--- | :---: | :---: | :---: | :--- | :--- |
| Forward Voltage, $\mathrm{V}_{\mathrm{F}}$ |  | 1.4 | 1.5 | V | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| Reverse Voltage, $\mathrm{V}_{\mathrm{R}}$ | 5.0 |  |  | V | $\mathrm{I}_{\mathrm{R}}=10 \mu \mathrm{~A}$ |
| Radiant Power, $\mathrm{P}_{\mathrm{O}}$ | 4.5 |  | mW | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |  |
| Peak Wavelength, $\lambda_{\mathrm{P}}$ |  | 850 | nm | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |  |
| Spectrum Width, Half Power, $\Delta \lambda$ | 40 | nm | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |  |  |
| Optical Rise Time, $\mathrm{T}_{\mathrm{R}}$ | 20 | ns | $\mathrm{I}_{\mathrm{FP}}=100 \mathrm{~mA}$ |  |  |
| Optical Fall Time, $\mathrm{T}_{\mathrm{F}}$ | 20 | ns | $\mathrm{I}_{\mathrm{FP}}=100 \mathrm{~mA}$ |  |  |

Wait Characteristics, $V_{D D}=3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, Gain $=16$, WEN $=1$ (unless otherwise noted)

| Parameter | Min | Typ | Max | Units | Test Conditions |
| :--- | :---: | :---: | :---: | :--- | :--- |
| Wait Step Size |  | 2.72 |  | ms | WTIME = 0xff |
| Wait Number of Step | 1 |  | 256 | steps |  |

Characteristics of the SDA and SCL bus lines, $\mathrm{V}_{\mathrm{DD}}=3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{\dagger}$

| Parameter | Symbol | STANDARD-MODE |  | FAST-MODE |  | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Max. |  |
| SCL clock frequency | $\mathrm{f}_{\text {SCL }}$ | 0 | 100 | 0 | 400 | kHz |
| Hold time (repeated) START condition. <br> After this period, the first clock pulse is generated | $\mathrm{t}_{\text {HD; }}$ STA | 4.0 | - | 0.6 | - | $\mu \mathrm{s}$ |
| LOW period of the SCL clock | tLOW | 4.7 | - | 1.3 | - | $\mu s$ |
| HIGH period of the SCL clock | $\mathrm{t}_{\mathrm{HIGH}}$ | 4.0 | - | 0.6 | - | $\mu \mathrm{s}$ |
| Set-up time for a repeated START condition | tSU;STA | 4.7 | - | 0.6 | - | $\mu \mathrm{s}$ |
| Data hold time | thD;DAT | 0 | - | 0 | - | ns |
| Data set-up time | $\mathrm{t}_{\text {SU; }}$ DAT | 250 | - | 100 | - | ns |
| Rise time of both SDA and SCL signals | $\mathrm{tr}_{\mathrm{r}}$ | - | 1000 | - | 300 | ns |
| Fall time of both SDA and SCL signals | $\mathrm{t}_{\mathrm{f}}$ | - | 300 | - | 300 | ns |
| Set-up time for STOP condition | tsu;STO | 4.0 | - | 0.6 | - | $\mu \mathrm{s}$ |
| Bus free time between a STOP and START condition | $\mathrm{t}_{\text {BUF }}$ | 4.7 | - | 1.3 | - | $\mu \mathrm{s}$ |
| Capacitive load for each bus line | $\mathrm{C}_{\mathrm{b}}$ | - | 400 | - | 400 | pF |
| Noise margin at the LOW level for each connected device (including hysteresis) | $\mathrm{V}_{\mathrm{nL}}$ | $0.1 \mathrm{~V}_{\text {BUS }}$ | - | 0.1V $\mathrm{V}_{\text {BUS }}$ | - | V |
| Noise margin at the HIGH level for each connected device (including hysteresis) | $\mathrm{V}_{\mathrm{nH}}$ | $0.2 \mathrm{~V}_{\text {BUS }}$ | - | $0.2 \mathrm{~V}_{\text {BUS }}$ | - | V |

$\dagger$ Specified by design and characterization; not production tested.


## Figure $1.1^{2}$ C Bus Timing Diagram



Figure 2. Spectral Response


Figure 3b. ALS Sensor LUX vs. Meter LUX using Incandescent Light


Figure 4a. Normalized IDD vs. VDD


Figure 5. Normalized ALS Response vs. Angular Displacement


Figure 3a. ALS Sensor LUX vs. Meter LUX using Fluorescent Light


Figure 3c. ALS Sensor LUX vs. Meter LUX using Low Lux Fluorescent Light


Figure 4b. Normalized IDD vs. Temperature

## PRINCIPLES OF OPERATION

## System State Machine

The APDS-9900/9901 provides control of ALS, proximity detection and power management functionality through an internal state machine. After a power-on-reset, the device is in the sleep mode. As soon as the PON bit is set, the device will move to the start state. It will then continue through the Prox, Wait and ALS states. If these states are enabled, the device will execute each function. If the PON bit is set to a 0 , the state machine will continue until all conversions are completed and then go into a low power sleep mode.


Figure 6. Simplified State Diagram

NOTE: In this document, the nomenclature uses the bit field name in italics followed by the register number and bit number to allow the user to easily identify the register and bit that controls the function. For example, the power on (PON) is in register 0 , bit 0 . This is represented as PON (ro:b0).

## Ch0 and Ch1 Diodes

Conventional silicon detectors respond strongly to infrared light, which the human eye does not see. This can lead to significant error when the infrared content of the ambient light is high (such as with incandescent lighting) due to the difference between the silicon detector response and the brightness perceived by the human eye.

This problem is overcome in the APDS-9900/9901 through the use of two photodiodes. One of the photodiodes, referred to as the Ch0 channel, is sensitive to both visible and infrared light while the second photodiode is sensitive primarily to infrared light. Two integrating ADCs convert the photodiode currents to digital outputs. The CH1DATA digital value is used to compensate for the effect of the infrared component of light on the CH0DATA digital value. The ADC digital outputs from the two channels are used in a formula to obtain a value that approximates the human eye response in units of Lux.

## ALS Operation

The ALS engine contains ALS gain control (AGAIN) and two integrating analog-to-digital converters (ADC) for the Ch0 and Ch1 photodiodes. The ALS integration time (ALSIT) impacts both the resolution and the sensitivity of the ALS reading. Integration of both channels occurs simultaneously and upon completion of the conversion cycle, the results are transferred to the Ch 0 and CH 1 data registers (CDATAx and IRDATAx). This data is also referred to as channel "count". The transfers are double-buffered to ensure that invalid data is not read during the transfer. After the transfer, the device automatically moves to the next state in accordance with the configured state machine.


Figure 7. ALS Operation

The ALS Timing register value (ATIME) for programming the integration time (ALSIT) is a 2's complement values. The ALS Timing register value can be calculated as follows:
ATIME $=256-$ ALSIT $/ 2.72 \mathrm{~ms}$
Inversely, the integration time can be calculated from the register value as follows:
ALSIT $=2.72 \mathrm{~ms}$ * ( $256-$ ATIME)
For example, if a 100 ms integration time is needed, the device needs to be programmed to:
ATIME $=256-(100 / 2.72)=256-37=219=0 x D B$
Conversely, the programmed value of $0 x C 0$ would correspond to:
ALSIT $=(256-0 x C 0) * 2.72=64 * 2.72=172 \mathrm{~ms}$.
Note: 2.72 ms can be estimated as 87 / 32. Multiply by 87 the shift by 5 bits.

## Calculating ALS Lux

## Definition:

CH0DATA $=256$ * CDATAH (r0x15) + CDATAL (r0x14)
CH1DATA $=256 *$ IRDATAH $(r 0 \times 17)+$ IRDATAL $(r 0 \times 16)$
IAC = IR Adjusted Count
LPC = Lux per Count
ALSIT = ALS Integration Time (ms)
AGAIN = ALS Gain
DF = Device Factor, DF = 52 for APDS-9900/9901
GA $=$ Glass (or Lens) Attenuation Factor
B, C, D - Coefficients
Lux Equation:
IAC1 $=$ CH0DATA $-\mathrm{B} \times$ CH1DATA
IAC2 $=\mathrm{C} \times$ CH0DATA $-\mathrm{D} \times \mathrm{CH} 1$ DATA
IAC $=\operatorname{Max}(I A C 1, I A C 2,0)$
$\mathrm{LPC}=\mathrm{GA} \times \mathrm{DF} /(\mathrm{ALSIT} \times \mathrm{AGAIN})$
Lux $=$ IAC $\times$ LPC
Coefficients in open air:
$\mathrm{GA}=0.48$
B $=2.23$
$C=0.7$
D $=1.42$

## Sample Lux Calculation in Open Air

Assume the following constants:
ALSIT $=400$
AGAIN = 1
LPC $=$ GA $\times$ DF $/($ ALSIT $\times$ AGAIN $)$
LPC $=0.48 \times 52 /(400 \times 1)$
LPC $=0.06$
Assume the following measurements:
CHODATA $=5000$
CH1DATA $=525$
Then:
IAC1 $=5000-2.23 \times 525=3829$
IAC2 $=0.7 \times 5000-1.42 \times 525=2755$
IAC $=\operatorname{Max}(3829,2755,0)=3829$
Lux:
Lux = IAC X LPC
Lux $=3829 \times 0.06$
Lux = 230
Note: please refer to application note for coefficient GA, B, C and D calculation with window.

## Recommend ALS Operations



Figure 8. Gain and Integration Time to Lux without IR
With the programming versatility of the integration time and gain, it can be difficult to understand when to use the different modes. Figure 8 shows a log-log plot of the Lux vs. integration time and gain with a spectral factor of unity and no IR present.
The maximum illuminance which can be measured is ~10k Lux with no IR present. The intercept with a count of 1 shows the resolution of each setting. The Lux values in the table increase as the SF increases (spectral attenuation increases). For example, if a $10 \%$ transmissive glass is used, the Lux values would all be multiplied by 10. The Lux values in the table decrease as the IR Factor decreases. For example, with a $10 \%$ IR Factor, which corresponds to a strong incandescent light, the Lux value would need to be divided by 10.
There are many factors that will impact the decision on which value to use for integration time and gain. One of the first factors is $50 / 60 \mathrm{~Hz}$ ripple rejection for fluorescent lighting. The programmed value needs to be multiples of $10 / 8.3 \mathrm{~ms}$ or the half cycle time. Both frequencies can be rejected with a programmed value of 50 ms (ATIME $=$ 0xED). With this value, the resolution will be 1.3 Lux per count. If higher resolution is needed, a longer integration time may be needed. In this case, the integration time should be programmed in multiples of 50 .

The light level is the next determining factor for configuring device settings. Under bright conditions, the count will be fairly high. If a low light measurement is needed, a higher gain and/or longer integration time will be needed. As a general rule, it is recommended to have a Ch0 channel count of at least 10 to accurately apply the Lux equation.

The digital accumulation is limited to 16 bits, which occurs at an integration time of 173 ms . This is the maximum recommended programmed integration time before increasing the gain. ( 150 ms is the maximum to reduce the fluorescent ripple.)

## Proximity Detection

Proximity sensing uses an internal IR LED light source to emit light which is then viewed by the integrated light detector to measure the amount of reflected light when an object is in the light path. The amount of light detected from a reflected surface can then be used to determine an object's proximity to the sensor. The APDS-9900/9901 is factory calibrated to meet the requirement of proximity sensing of $100+/-20 \mathrm{~mm}$, thus eliminating the need for factory calibration of the end equipment. When the APDS9900/9901 is placed behind a typical glass surface, the proximity detection achieved is around 25 to 40 mm , thus providing an ideal touch-screen disable.
The APDS-9900/9901 has controls for the number of IR pulses (PPCOUNT), the integration time (PTIME), the LED drive current (PDRIVE) and the photodiode configuration (PDIODE). At the end of the integration cycle, the results are latched into the proximity data (PDATA) register.

The LED drive current is controlled by a regulated current sink on the LDR pin. This feature eliminates the need to use a current limiting resistor to control LED current. The LED drive current can be configured for $12.5 \mathrm{~mA}, 25 \mathrm{~mA}, 50 \mathrm{~mA}$, or 100 mA . For higher LED drive requirements, an external $P$ type transistor can be used to control the LED current.

The number of LED pulses can be programmed to a value of 1 to 255 pulses as needed. Increasing the number of LED pulses at a given current will increase the sensor sensitivity. Sensitivity grows by the square root of the number of pulses. Each pulse has a $16 \mu \mathrm{~S}$ period.

The proximity integration time (PTIME) is the period of time that the internal ADC converts the analog signal to a digital count. It is recommend that this be set to a minimum of PTIME $=0 \times F F$ or 2.72 ms .


Figure 9. Proximity IR LED Waveform

## Optical Design Considerations

The APDS-9900/9901 simplifies the optical system design by eliminating the need for light pipes and improves system optical efficiency by providing apertures and package shielding which will reduce crosstalk when placed in the final system. By reducing the IR LED to glass surface crosstalk, proximity performance is greatly improved and enables a wide range of cell phone applications utilizing the APDS-9900/9901. The module package design has been optimized for minimum package foot print and short distance proximity of 100 mm typical. The spacing between the glass surface and package top surface is critical to controlling the crosstalk. If the package to top surface spacing gap, window thickness and transmittance are met, there should be no need to add additional components (such as a barrier) between the LED and photodiode. Thus with some simple mechanical design implementations, the APDS-9900/9901 will perform well in the end equipment system.

## APDS-9900/9901 Module Optimized design parameters

- Window thickness, $\mathrm{t} \leq 1.0 \mathrm{~mm}$
- Air gap, $\mathrm{g} \leq 0.5 \mathrm{~mm}$
- Assuming window IR transmittance $90 \%$

The APDS-9900/9901 is available in a low profile package that contains optics which provides optical gain on botht the LED and the sensor side of the package. The device has a package $Z$ height of 1.35 mm and will support air gap of $<=0.5 \mathrm{~mm}$ between the glass and the package. The assumption of the optical system level design is that glass surface above the module is $<=$ to 1.0 mm .

By integrating the micro-optics in the package, the IR energy emitted can be reduced thus conserving the precious battery life in the application.

The system designer has the ability to optimize their designs for slim form factor $Z$ height as well as improve the proximity sensing, save battery power and disable the touch screen in a cellular phone.


## Figure 10. Proximity Detection



Figure 11a. PS Output vs. Distance, at Various Pulse number (LED drive Current). No glass in front of the module, $\mathbf{1 8 \%}$ Kodak Grey Card.


Figure 11b. PS Output vs. Distance, at Various Pulse number (LED drive Current). No glass in front of the module, $\mathbf{9 0 \%}$ Kodak Grey Card.

## Interrupts

The interrupt feature of the APDS-9900/9901 simplifies and improves system efficiency by eliminating the need to poll the sensor for a light intensity or proximity value. The interrupt mode is determined by the PIEN or AIEN field in the ENABLE register.

The APDS-9900/9901 implements four 16-bit-wide interrupt threshold registers that allow the user to define thresholds above and below a desired light level. For ALS, an interrupt can be generated when the ALS Ch0 data (CDATA) exceeds the upper threshold value (AIHTx) or falls below the lower threshold (AILTx). For proximity,
an interrupt can be generated when the proximity data (PDATA) exceeds the upper threshold value (PIHTx) or falls below the lower threshold (PILTx).

To further control when an interrupt occurs, the APDS9900/9901 provides an interrupt persistence feature. This feature allows the user to specify a number of conversion cycles for which an event exceeding the ALS interrupt threshold must persist (APERS) or the proximity interrupt threshold must persist (PPERS) before actually generating an interrupt. Refer to the register descriptions for details on the length of the persistence.


Figure 12. Programmable Interrupt

## State Diagram

The following shows a more detailed flow for the state machine. The device starts in the sleep mode. The PON bit is written to enable the device. If the PEN bit is set, the state machine will step through the proximity states of proximity accumulate and then proximity ADC conversion. As soon as the conversion is complete, the state machine will move to the following state.

If the WEN bit is set, the state machine will then cycle through the wait state. If the WLONG bit is set, the wait cycles are extended by $12 x$ over normal operation. When the wait counter terminates, the state machine will step to the ALS state.

When AEN bit is set, the state machine will step through the ALS states of ALS accumulate and then ALS ADC conversion. In this case, a minimum of 1 integration time step should be programmed. The ALS state machine will continue until it reaches the terminal count at which point the data will be latched in the ALS register and the interrupt set, if enabled.

## Power Management

Power consumption can be controlled through the use of the wait state timing since the wait state consumes only $70 \mu \mathrm{~A}$ of power. The following shows an example of using the power management feature to achieve an average power consumption of $158 \mu \mathrm{~A}$ of current with $4-100 \mathrm{~mA}$ pulses of proximity detection and 50 ms of ALS detection.


Figure 13. Extended State Diagram


Figure 14. Power Consumption Calculations

## Basic Software Operation

The following pseudo-code shows how to do basic initialization of the APDS-9900/9901.

```
uint8 ATIME, PIME, WTIME, PPCOUNT;
ATIME = 0xff; // 2.7 ms - minimum ALS integration time
WTIME = 0xff; // 2.7 ms - minimum Wait time
PTIME = 0xff; // 2.7 ms - minimum Prox integration time
PPCOUNT = 1; // Minimum prox pulse count
WriteRegData(0, 0); //Disable and Powerdown
WriteRegData (1, ATIME);
WriteRegData (2, PTIME);
WriteRegData (3, WTIME);
WriteRegData (0xe, PPCOUNT);
uint8 PDRIVE, PDIODE, PGAIN, AGAIN;
PDRIVE = 0; //100mA of LED Power
PDIODE = 0x20; // CH1 Diode
PGAIN = 0; //1x Prox gain
AGAIN = 0; //1x ALS gain
WriteRegData (0xf, PDRIVE | PDIODE|PGAIN | AGAIN);
uint8 WEN, PEN, AEN, PON;
WEN = 8; // Enable Wait
PEN = 4; // Enable Prox
AEN = 2; // Enable ALS
PON = 1;// Enable Power On
WriteRegData (0, WEN | PEN | AEN | PON); // WriteRegData(0,0xOf);
Wait(12); //Wait for }12\textrm{ms
int CH0_data, CH1_data, Prox_data;
CH0_data = Read_Word(0x14);
CH1_data = Read_Word(0x16);
Prox_data = Read_Word(0x18);
WriteRegData(uint8 reg, uint8 data)
{
    m_I2CBus.Writel2C(0x39, 0x80 | reg, 1, &data);
}
uint16 Read_Word(uint8 reg);
{
    uint8 barr[2];
    m_I2CBus.ReadI2C(0x39, 0xA0 | reg, 2, ref barr);
    return (uint16)(barr[0] + 256 * barr[1]);
}
```


## I2C Protocol

Interface and control of the APDS-9900/9901 is accomplished through an $1^{2} \mathrm{C}$ serial compatible interface (standard or fast mode) to a set of registers that provide access to device control functions and output data. The device supports a single slave address of $0 \times 39$ hex using 7 bit addressing protocol. (Contact factory for other addressing options.)

The ${ }^{12} \mathrm{C}$ standard provides for three types of bus transaction: read, write and a combined protocol. During a write operation, the first byte written is a command byte followed by data. In a combined protocol, the first byte
written is the command byte followed by reading a series of bytes. If a read command is issued, the register address from the previous command will be used for data access. Likewise, if the MSB of the command is not set, the device will write a series of bytes at the address stored in the last valid command with a register address. The command byte contains either control information or a 5 bit register address. The control commands can also be used to clear interrupts. For a complete description of $I^{2} \mathrm{C}$ protocols, please review the $I^{2} \mathrm{C}$ Specification at: http://www.NXP. com

## Start and Stop conditions



## Data transfer on $\mathrm{I}^{2} \mathrm{C}$-bus



## A complete data transfer



A Acknowledge (0)
N Not Acknowledged (1)
P Stop Condition
R Read (1)
S Start Condition
Sr Repeated Start Condition
W Write (0)
... Continuation of protocol
Master-to-Slave
Slave-to-Master

| 1 | 7 | 1 | 1 | 8 | 1 |  | 8 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| S | Slave Address | W | A | Command Code | A | Data | A | P |

## $I^{2}$ C Write Protocol

| 1 | 7 | 1 | 1 | 8 | 1 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| S | Slave Address | W | A | Command Code | A | P |

I2C Write Protocol (Clear Interrupt)

$1^{2}$ C Write Word Protocol

| 1 | 7 | 1 | 1 | 8 | 1 | 7 | 1 | 1 | 1 | 1 | 1 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| S | Slave Address | W | A | Command Code | A | Sr | Slave Address | R | A | Data | N | P |

${ }^{2}$ C Read Protocol - Combined Format

| 1 | 7 | 1 | 1 | 8 | 1 |  |  |  |  |  |  |  |  | 1 | 7 | 1 | 1 | 8 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| S | Slave Address | W | A | Command Code | A | Sr | Slave Address | R | A | Data Low | A |  |  |  |  |  |  |  |  |


| 8 | 1 | 1 |
| :---: | :---: | :---: |
| Data High | N | P |

## $1^{2}$ C Read Word Protocol

## Register Set

The APDS-9900/9901 is controlled and monitored by data registers and a command register accessed through the serial interface. These registers provide for a variety of control functions and can be read to determine results of the ADC conversions.

| ADDRESS | RESISTER NAME | R/W | REGISTER FUNCTION | Reset Value |
| :---: | :---: | :---: | :---: | :---: |
| - | COMMAND | W | Specifies register address | 0x00 |
| 0x00 | ENABLE | R/W | Enable of states and interrupts | 0x00 |
| 0x01 | ATIME | R/W | ALS ADC time | 0x00 |
| 0x02 | PTIME | R/W | Proximity ADC time | 0xFF |
| $0 \times 03$ | WTIME | R/W | Wait time | 0xFF |
| 0x04 | AILTL | R/W | ALS interrupt low threshold low byte | 0x00 |
| 0x05 | AILTH | R/W | ALS interrupt low threshold hi byte | 0x00 |
| 0x06 | AIHTL | R/W | ALS interrupt hi threshold low byte | 0x00 |
| $0 \times 07$ | AIHTL | R/W | ALS interrupt hi threshold hi byte | 0x00 |
| $0 \times 08$ | PILTL | R/W | Proximity interrupt low threshold low byte | 0x00 |
| 0x09 | PILTH | R/W | Proximity interrupt low threshold hi byte | 0x00 |
| $0 \times 0 \mathrm{~A}$ | PIHTL | R/W | Proximity interrupt hi threshold low byte | 0x00 |
| 0x0B | PIHTH | R/W | Proximity interrupt hi threshold hi byte | 0x00 |
| 0xOC | PERS | R/W | Interrupt persistence filters | 0x00 |
| 0x0D | CONFIG | R/W | Configuration | 0x00 |
| 0x0E | PPCOUNT | R/W | Proximity pulse count | 0x00 |
| 0x0F | CONTROL | R/W | Gain control register | 0x00 |
| $0 \times 11$ | REV | R | Revision Number | Rev |
| $0 \times 12$ | ID | R | Device ID | ID |
| $0 \times 13$ | STATUS | R | Device status | 0x00 |
| $0 \times 14$ | CDATAL | R | Ch0 ADC low data register | 0x00 |
| 0x15 | CDATAH | R | Ch0 ADC high data register | 0x00 |
| $0 \times 16$ | IRDATAL | R | Ch1 ADC low data register | 0x00 |
| $0 \times 17$ | IRDATAH | R | Ch1 ADC high data register | 0x00 |
| $0 \times 18$ | PDATAL | R | Proximity ADC low data register | 0x00 |
| 0x19 | PDATAH | R | Proximity ADC high data register | 0x00 |

The mechanics of accessing a specific register depends on the specific protocol used. See the section on $I^{2} \mathrm{C}$ protocols on the previous pages. In general, the COMMAND register is written first to specify the specific control/status register for following read/write operations.

## Command Register

The command registers specifies the address of the target register for future write and read operations.


## Enable Register (0x00)

The ENABLE register is used primarily to power the APDS-9900/9901 device up and down as shown in Table 4.

|  | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | Address |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ENABLE | Reserved | Reserved | PIEN | AIEN | WEN | PEN | AEN | PON | 0x00 |


| FIELD | BITS | DESCRIPTION |
| :--- | :--- | :--- |
| Reserved | $7: 6$ | Reserved. Write as 0. |
| PIEN | 5 | Proximity Interrupt Enable. When asserted, permits proximity interrupts to be generated. |
| AIEN | 4 | ALS Interrupt Enable. When asserted, permits ALS interrupt to be generated. |
| WEN | 3 | Wait Enable. This bit activates the wait feature. Writing a 1 activates the wait timer. <br> Writing a 0 disables the wait timer. |
| PEN | 2 | Proximity Enable. This bit activates the proximity function. Writing a 1 enables proximity. <br> Writing a 0 disables proximity. |
| AEN | 1 | ALS Enable. This bit actives the two channel ADC. Writing a 1 activates the ADC. <br> Writing a 0 disables the ADC. |
| PON | 0 | Power ON. This bit activates the internal oscillator to permit the timers and ADC channels to operate. <br> Writing a 1 activates the oscillator. Writing a 0 disables the oscillator. |

Notes:

1. A 2.72 ms delay is automatically inserted prior to entering the ADC cycle, independent of the WEN bit.
2. Both AEN and PON must be asserted before the ADC channels will operate correctly.
3. During writes and reads over the $I^{2} \mathrm{C}$ interface, this bit is overridden and the oscillator is enabled, independent of the state of PON.
4. A minimum interval of 2.72 ms must pass after PON is asserted before either proximity or an ALS can be initiated. This required time is enforced by the hardware in cases where the firmware does not provide it.

## ALS Timing Register (0x01)

The ALS timing register controls the integration time of the ALS Ch0 and Ch1 channel ADCs in 2.72 ms increments.

| FIELD | BITS | DESCRIPTION |  |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- |
| ATIME | $7: 0$ | VALUE | CYCLES | TIME (ALSIT) | Max Count |
|  |  | 0xff | 1 | 2.72 ms | 1023 |
|  | 0xf6 | 10 | 27.2 ms | 10239 |  |
|  | $0 \times d b$ | 37 | 100.64 ms | 37887 |  |
|  | $0 \times 0$ | 64 | 174.08 ms | 65535 |  |
|  | $0 \times 00$ | 256 | 696.32 ms | 65535 |  |

## Proximity Time Control Register (0x02)

The proximity timing register controls the integration time of the proximity ADC in 2.72 ms increments. It is recommended that this register be programmed to a value of 0xff (1 cycle, 1023 bits).

| FIELD | BITS | DESCRIPTION |  |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- |
| PTIME | $7: 0$ | VALUE | CYCLES | TIME | Max Count |
|  |  | $0 x f f$ | 1 | 2.72 ms | 1023 |

## Wait Time Register (0x03)

Wait time is set 2.72 ms increments unless the WLONG bit is asserted in which case the wait times are 12 x longer. WTIME is programmed as a 2 's complement number.

| FIELD | BITS | DESCRIPTION |  |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- |
| WTIME | $7: 0$ | REGISTER VALUE | WALL TIME | TIME (WLONG =0) | TIME (WLONG = 1) |
|  |  | 0xff | 1 | 2.72 ms | 0.032 sec |
|  |  | 0xb6 | 74 | 201.29 ms | 2.37 sec |
|  | $0 \times 00$ | 256 | 696.32 ms | 8.19 sec |  |

Notes:

1. The Write Byte protocol cannot be used when WTIME is greater than 127.
2. The Proximity Wait Time Register should be configured before PEN and/or AEN is/are asserted.

## ALS Interrupt Threshold Register (0x04-0x07)

The ALS interrupt threshold registers provides the values to be used as the high and low trigger points for the comparison function for interrupt generation. If the value generated by the ALS channel crosses below the low threshold specified, or above the higher threshold, an interrupt is asserted on the interrupt pin.

| REGISTER | ADDRESS | BITS | DESCRIPTION |
| :--- | :--- | :--- | :--- |
| AILTL | $0 \times 04$ | $7: 0$ | ALS Ch0 channel low threshold lower byte |
| AILTH | $0 \times 05$ | $7: 0$ | ALS Ch0 channel low threshold upper byte |
| AIHTL | $0 \times 06$ | $7: 0$ | ALS Ch0 channel high threshold lower byte |
| AIHTH | $0 \times 07$ | $7: 0$ | ALS Ch0 channel high threshold upper byte |

Note: The Write Word protocol should be used to write byte-paired registers.

## Proximity Interrupt Threshold Register ( $0 \times 08$ - 0x0B)

The proximity interrupt threshold registers provide the values to be used as the high and low trigger points for the comparison function for interrupt generation. If the value generated by proximity channel crosses below the lower threshold specified, or above the higher threshold, an interrupt is signaled to the host processor.

| REGISTER | ADDRESS | BITS | DESCRIPTION |
| :--- | :--- | :--- | :--- |
| PILTL | $0 \times 08$ | $7: 0$ | Proximity ADC channel low threshold lower byte |
| PILTH | $0 \times 09$ | $7: 0$ | Proximity ADC channel low threshold upper byte |
| PIHTL | $0 \times 0 A$ | $7: 0$ | Proximity ADC channel high threshold lower byte |
| PIHTH | $0 \times 0 B$ | $7: 0$ | Proximity ADC channel high threshold upper byte |

## Persistence Register (0x0C)

The persistence register controls the filtering interrupt capabilities of the device. Configurable filtering is provided to allow interrupts to be generated after each ADC integration cycle or if the ADC integration has produced a result that is outside of the values specified by threshold register for some specified amount of time. Separate filtering is provided for proximity and ALS functions.
ALS interrupts are generated by looking only at the ADC integration results of channel 0 .


## Configuration Register (0x0D)

The configuration register sets the wait long time.

|  | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CONFIG |  |  |  |  |  |  | WLONG | Reserved | 0x0D |


| FIELD | BITS | DESCRIPTION |
| :--- | :--- | :--- |
| Reserved | $7: 2$ | Reserved. Write as 0. |
| WLONG | 1 | Wait Long. When asserted, the wait cycles are increased by a factor 12x from that programmed in <br> the WTIME register. |
| Reserved | 0 | Reserved. Write as 0. |

## Proximity Pulse Count Register (0x0E)

The proximity pulse count register sets the number of proximity pulses that will be transmitted. When proximity detection is enabled, a proximity detect cycle occurs after each ALS cycle. PPCOUNT defines the number of pulses to be transmitted at a 62.5 kHz rate.

|  | 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |

## Control Register (0x0F)

The Gain register provides eight bits of miscellaneous control to the analog block. These bits typically control functions such as gain settings and/or diode selection.


| $\frac{\text { FIELD }}{\text { PDRIVE }}$ | $\begin{aligned} & \text { BITS } \\ & \hline 7: 6 \end{aligned}$ | DESCRIPTION |  |
| :---: | :---: | :---: | :---: |
|  |  | LED Drive St |  |
|  |  | FIELD VALUE | LED STRENGTH |
|  |  | 00 | 100 mA |
|  |  | 01 | 50 mA |
|  |  | 10 | 25 mA |
|  |  | 11 | 12.5 mA |
| PDIODE | 5:4 | Proximity Diode Select. |  |
|  |  | FIELD VALUE | DIODE SELECTION |
|  |  | 00 | Reserved |
|  |  | 01 | Reserved |
|  |  | 10 | Proximity uses the Ch1 diode |
|  |  | 11 | Reserved |
| PGAIN | 3:2 | Proximity Gain Control. |  |
|  |  | FIELD VALUE | Proximity GAIN VALUE |
|  |  | 00 | 1X Gain |
|  |  | 01 | Reserved |
|  |  | 10 | Reserved |
|  |  | 11 | Reserved |
| AGAIN | 1:0 | ALS Gain Control. |  |
|  |  | FIELD VALUE | ALS GAIN VALUE |
|  |  | 00 | 1X Gain |
|  |  | 01 | 8X Gain |
|  |  | 10 | 16X Gain |
|  |  | 11 | 120X Gain |

## Revision number Register (0x11)

The Revision number register provides the silicon revision number. The Rev ID is a read-only register whose value never changes.

| REV | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | $0 \times 11$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | ID |  |  |  |  |  |  |  |  |
| FIELD | BITS |  |  |  |  |  |  |  |  |
| REV | 7:0 | Revision number identification |  |  |  |  |  |  |  |
|  |  | $0 \times 0$ |  |  |  |  |  |  |  |

## Device ID Register (0x12)

The ID register provides the value for the part number. The ID register is a read-only register.

| ID | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | 0x12 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Device ID |  |  |  |  |  |  |  |  |
| FIELD | BITS |  |  |  |  |  |  |  |  |
| ID | 7:0 |  | id |  |  |  |  |  |  |
|  |  |  | -9 |  |  |  |  |  |  |
|  |  |  | -9 |  |  |  |  |  |  |

## Status Register (0x13)

The Status Register provides the internal status of the device. This register is read only.


| FIELD | BITS | DESCRIPTION |
| :--- | :--- | :--- |
| Reserved | $7: 6$ | Reserved. Write as 0. |
| PINT | 5 | Proximity Interrupt. Indicates that the device is asserting a proximity interrupt. |
| AINT | 4 | ALS Interrupt. Indicates that the device is asserting an ALS interrupt. |
| Reserved | $3: 2$ | Reserved. Write as 0. |
| PVALID | 1 | PS Valid. Indicates that the PS has completed an integration cycle. |
| AVALID | 0 | ALS Valid. Indicates that the ALS Ch0/Ch1 channels have completed an integration cycle. |

## ALS Data Registers (0x14-0x17)

ALS Ch0 and CH1 data are stored as two 16-bit values. To ensure the data is read correctly, a two byte read ${ }^{2}$ C transaction should be utilized with a read word protocol bit set in the command register. With this operation, when the lower byte register is read, the upper eight bits are stored into a shadow register, which is read by a subsequent read to the upper byte. The upper register will read the correct value even if additional ADC integration cycles end between the reading of the lower and upper registers.

| REGISTER | ADDRESS | BITS | DESCRIPTION |
| :--- | :--- | :--- | :--- |
| CDATA | $0 \times 14$ | $7: 0$ | ALS Ch0 channel data low byte |
| CDATAH | $0 \times 15$ | $7: 0$ | ALS Ch0 channel data high byte |
| IRDATA | $0 \times 16$ | $7: 0$ | ALS Ch1 channel data low byte |
| IRDATAH | $0 \times 17$ | $7: 0$ | ALS Ch1 channel data high byte |

## Proximity DATA Register (0x18-0x19)

Proximity data is stored as a 16-bit value. To ensure the data is read correctly, a two byte read $\mathrm{I}^{2} \mathrm{C}$ transaction should be utilized with a read word protocol bit set in the command register. With this operation, when the lower byte register is read, the upper eight bits are stored into a shadow register, which is read by a subsequent read to the upper byte. The upper register will read the correct value even if additional ADC integration cycles end between the reading of the lower and upper registers.

| REGISTER | ADDRESS | BITS | DESCRIPTION |
| :--- | :--- | :--- | :--- |
| PDATA | $0 \times 18$ | $7: 0$ | Proximity data low byte |
| PDATAH | $0 \times 19$ | $7: 0$ | Proximity data high byte |

## Application Information: Hardware

The application hardware circuit for using implementing an ALS and Proximity system solution is quite simple with the APDS-9900/9901 and is shown in following figure. The $1 \mu \mathrm{~F}$ decoupling capacitors should be low ESR to reduce noise. It further recommended to maximize system performance the use of power and ground planes is recommended in the PCB. If mounted on a flexible circuit, the power and ground traces back to the PCB should be sufficiently wide enough to have a low resistance, such as < 1 ohm.


Figure 15. Circuit implementation for ALS plus Proximity solution using the APDS-9900/9901

Package Outline Dimensions


PCB Pad Layout
Suggested PCB pad layout guidelines for the Dual Flat No-Lead surface mount package are shown below.


[^0]
## Tape Dimensions



AO
All dimensions unit: mm

## Reel Dimensions



## Moisture Proof Packaging

All APDS-9900/9901 options are shipped in moisture proof package. Once opened, moisture absorption begins. This part is compliant to JEDEC MSL 3.


Baking Conditions:

| Package | Temperature | Time |
| :--- | :--- | :--- |
| In Reel | $60^{\circ} \mathrm{C}$ | 48 hours |
| In Bulk | $100^{\circ} \mathrm{C}$ | 4 hours |

If the parts are not stored in dry conditions, they must be baked before reflow to prevent damage to the parts.
Baking should only be done once.

## Recommended Storage Conditions:

| Storage Temperature | $10^{\circ} \mathrm{C}$ to $30^{\circ} \mathrm{C}$ |
| :--- | :--- |
| Relative Humidity | below $60 \% \mathrm{RH}$ |

## Time from unsealing to soldering:

After removal from the bag, the parts should be soldered within 168 hours if stored at the recommended storage conditions. If times longer than 168 hours are needed, the parts must be stored in a dry box

## Recommended Reflow Profile



|  |  |  | Maximum $\Delta \mathrm{T} / \Delta$ time <br> or Duration |
| :--- | :--- | :--- | :--- |
| Process Zone | Symbol | $\Delta \mathbf{T}$ | $25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |
| Heat Up | $3^{\circ} \mathrm{C} / \mathrm{s}$ |  |  |
| Solder Paste Dry | $\mathrm{P}, \mathrm{R} 2$ | $150^{\circ} \mathrm{C}$ to $200^{\circ} \mathrm{C}$ | 100 s to 180 s |
| Solder Reflow | $200^{\circ} \mathrm{C}$ to $260^{\circ} \mathrm{C}$ | $3^{\circ} \mathrm{C} / \mathrm{s}$ |  |
|  | $\mathrm{P} 3, \mathrm{R} 4$ | $260^{\circ} \mathrm{C}$ to $200^{\circ} \mathrm{C}$ | $-6^{\circ} \mathrm{C} / \mathrm{s}$ |
| Cool Down | $\mathrm{P} 4, \mathrm{R} 5$ | $200^{\circ} \mathrm{C}$ to $25^{\circ} \mathrm{C}$ | $-6^{\circ} \mathrm{C} / \mathrm{s}$ |
| Time maintained above liquidus point $217^{\circ} \mathrm{C}$ | $>217^{\circ} \mathrm{C}$ | 60 s to 120 s |  |
| Peak Temperature | $260^{\circ} \mathrm{C}$ | - |  |
| Time within $5^{\circ} \mathrm{C}$ of actual Peak Temperature | $>255^{\circ} \mathrm{C}$ | 20 s to 40 s |  |
| Time $25^{\circ} \mathrm{C}$ to Peak Temperature | $25^{\circ} \mathrm{C}$ to $260^{\circ} \mathrm{C}$ | 8 mins |  |

The reflow profile is a straight-line representation of a nominal temperature profile for a convective reflow solder process. The temperature profile is divided into four process zones, each with different $\Delta \mathrm{T} / \Delta$ time temperature change rates or duration. The $\Delta \mathrm{T} / \Delta$ time rates or duration are detailed in the above table. The temperatures are measured at the component to printed circuit board connections.

In process zone P1, the PC board and component pins are heated to a temperature of $150^{\circ} \mathrm{C}$ to activate the flux in the solder paste. The temperature ramp up rate, R 1 , is limited to $3^{\circ} \mathrm{C}$ per second to allow for even heating of both the PC board and component pins.

Process zone P2 should be of sufficient time duration (100 to 180 seconds) to dry the solder paste. The temperature is raised to a level just below the liquidus point of the solder.

Process zone P3 is the solder reflow zone. In zone P3, the temperature is quickly raised above the liquidus point of
solder to $260^{\circ} \mathrm{C}\left(500^{\circ} \mathrm{F}\right)$ for optimum results. The dwell time above the liquidus point of solder should be between 60 and 120 seconds. This is to assure proper coalescing of the solder paste into liquid solder and the formation of good solder connections. Beyond the recommended dwell time the intermetallic growth within the solder connections becomes excessive, resulting in the formation of weak and unreliable connections. The temperature is then rapidly reduced to a point below the solidus temperature of the solder to allow the solder within the connections to freeze solid.

Process zone P4 is the cool down after solder freeze. The cool down rate, R5, from the liquidus point of the solder to $25^{\circ} \mathrm{C}\left(77^{\circ} \mathrm{F}\right)$ should not exceed $6^{\circ} \mathrm{C}$ per second maximum. This limitation is necessary to allow the PC board and component pins to change dimensions evenly, putting minimal stresses on the component.

It is recommended to perform reflow soldering no more than twice.

# OCEAN CHIPS <br> Океан Электроники <br> Поставка электронных компонентов 

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

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- Поставка сложных, дефицитных, либо снятых с производства позиций;
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- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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[^0]:    Notes: all linear dimensions are in mm

